

High Efficiency LED, \varnothing 3 mm Tinted Undiffused Package

Description

The TLH.42.. series was developed for standard applications like general indicating and lighting purposes.

It is housed in a 3 mm tinted clear plastic package. The wide viewing angle of these devices provides a high on-off contrast.

Several selection types with different luminous intensities are offered. All LEDs are categorized in luminous intensity groups. The green and yellow LEDs are categorized additionally in wavelength groups.



That allows users to assemble LEDs with uniform appearance.

Features

- Choice of five bright colors
- Standard T-1 package
- Small mechanical tolerances
- Suitable for DC and high peak current
- Wide viewing angle
- Luminous intensity categorized
- Yellow and green color categorized
- Lead-free device

Applications

- Status lights
- OFF / ON indicator
- Background illumination
- Readout lights
- Maintenance lights
- Legend light

Parts Table

| Part | Color, Luminous Intensity | Angle of Half Intensity ($\pm\phi$) | Technology |
|----------|-----------------------------|---------------------------------------|--------------|
| TLHR4200 | Red, $I_V > 4$ mcd | 22 ° | GaAsP on GaP |
| TLHR4201 | Red, $I_V > 6.3$ mcd | 22 ° | GaAsP on GaP |
| TLHR4205 | Red, $I_V > 10$ mcd | 22 ° | GaAsP on GaP |
| TLHO4200 | Soft orange, $I_V > 4$ mcd | 22 ° | GaAsP on GaP |
| TLHO4201 | Soft orange, $I_V > 10$ mcd | 22 ° | GaAsP on GaP |
| TLHY4200 | Yellow, $I_V > 4$ mcd | 22 ° | GaAsP on GaP |
| TLHY4201 | Yellow, $I_V > 6.3$ mcd | 22 ° | GaAsP on GaP |
| TLHY4205 | Yellow, $I_V > 10$ mcd | 22 ° | GaAsP on GaP |
| TLHG4200 | Green, $I_V > 6.3$ mcd | 22 ° | GaP on GaP |
| TLHG4201 | Green, $I_V > 10$ mcd | 22 ° | GaP on GaP |
| TLHG4205 | Green, $I_V > 16$ mcd | 22 ° | GaP on GaP |
| TLHP4200 | Pure green, $I_V > 2.5$ mcd | 22 ° | GaP on GaP |
| TLHP4201 | Pure green, $I_V > 6.3$ mcd | 22 ° | GaP on GaP |

Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

TLHR42.., TLHO42.., TLHY42.., TLHG42.., TLHP42..

| Parameter | Test condition | Symbol | Value | Unit |
|---|---|------------|---------------|--------------------|
| Reverse voltage | | V_R | 6 | V |
| DC Forward current | | I_F | 30 | mA |
| Surge forward current | $t_p \leq 10\text{ }\mu\text{s}$ | I_{FSM} | 1 | A |
| Power dissipation | $T_{amb} \leq 60\text{ }^{\circ}\text{C}$ | P_V | 100 | mW |
| Junction temperature | | T_j | 100 | $^{\circ}\text{C}$ |
| Operating temperature range | | T_{amb} | - 40 to + 100 | $^{\circ}\text{C}$ |
| Storage temperature range | | T_{stg} | - 55 to + 100 | $^{\circ}\text{C}$ |
| Soldering temperature | $t \leq 5\text{ s}$, 2 mm from body | T_{sd} | 260 | $^{\circ}\text{C}$ |
| Thermal resistance junction/ ambient | | R_{thJA} | 400 | K/W |

Optical and Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Red

TLHR42..

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|----------------------------------|--------------------------------|----------|-------------|-----|----------|-----|------|
| Luminous intensity ¹⁾ | $I_F = 10\text{ mA}$ | TLHR4200 | I_V | 4 | 8 | | mcd |
| | | TLHR4201 | I_V | 6.3 | 10 | | mcd |
| | | TLHR4205 | I_V | 10 | 15 | | mcd |
| Dominant wavelength | $I_F = 10\text{ mA}$ | | λ_d | 612 | | 625 | nm |
| Peak wavelength | $I_F = 10\text{ mA}$ | | λ_p | | 635 | | nm |
| Angle of half intensity | $I_F = 10\text{ mA}$ | | φ | | ± 22 | | deg |
| Forward voltage | $I_F = 20\text{ mA}$ | | V_F | | 2 | 3 | V |
| Reverse voltage | $I_R = 10\text{ }\mu\text{A}$ | | V_R | 6 | 15 | | V |
| Junction capacitance | $V_R = 0$, $f = 1\text{ MHz}$ | | C_j | | 50 | | pF |

¹⁾ in one Packing Unit $I_{Vmin}/I_{Vmax} \leq 0.5$

Soft Orange

TLHO42..

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|----------------------------------|--------------------------------|----------|-------------|-----|----------|-----|---------------|
| Luminous intensity ¹⁾ | $I_F = 10\text{ mA}$ | TLHO4200 | I_V | 4 | 10 | | mcd |
| | | TLHO4201 | I_V | 10 | 18 | | mcd |
| Dominant wavelength | $I_F = 10\text{ mA}$ | | λ_d | 598 | | 611 | nm |
| Peak wavelength | $I_F = 10\text{ mA}$ | | λ_p | | 605 | | nm |
| Angle of half intensity | $I_F = 10\text{ mA}$ | | φ | | ± 22 | | deg |
| Forward voltage | $I_F = 20\text{ mA}$ | | V_F | | 2.4 | 3 | V |
| Reverse current | $V_R = 6\text{ V}$ | | I_R | | | 10 | μA |
| Junction capacitance | $V_R = 0$, $f = 1\text{ MHz}$ | | C_j | | 50 | | pF |

¹⁾ in one Packing Unit $I_{Vmin}/I_{Vmax} \leq 0.5$



Yellow

TLHY42..

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|----------------------------------|--------------------------------|----------|-------------|-----|----------|-----|------|
| Luminous intensity ¹⁾ | $I_F = 10 \text{ mA}$ | TLHY4200 | I_V | 4 | 10 | | mcd |
| | | TLHY4201 | I_V | 6.3 | 15 | | mcd |
| | | TLHY4205 | I_V | 10 | 20 | | mcd |
| Dominant wavelength | $I_F = 10 \text{ mA}$ | | λ_d | 581 | | 594 | nm |
| Peak wavelength | $I_F = 10 \text{ mA}$ | | λ_p | | 585 | | nm |
| Angle of half intensity | $I_F = 10 \text{ mA}$ | | ϕ | | ± 22 | | deg |
| Forward voltage | $I_F = 20 \text{ mA}$ | | V_F | | 2.4 | 3 | V |
| Reverse voltage | $I_R = 10 \text{ }\mu\text{A}$ | | V_R | 6 | 15 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 50 | | pF |

¹⁾ in one Packing Unit $I_{Vmin}/I_{Vmax} \leq 0.5$

Green

TLHG42..

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|----------------------------------|--------------------------------|----------|-------------|-----|----------|-----|------|
| Luminous intensity ¹⁾ | $I_F = 10 \text{ mA}$ | TLHG4200 | I_V | 6.3 | 10 | | mcd |
| | | TLHG4201 | I_V | 10 | 15 | | mcd |
| | | TLHG4205 | I_V | 16 | 20 | | mcd |
| Dominant wavelength | $I_F = 10 \text{ mA}$ | | λ_d | 562 | | 575 | nm |
| Peak wavelength | $I_F = 10 \text{ mA}$ | | λ_p | | 565 | | nm |
| Angle of half intensity | $I_F = 10 \text{ mA}$ | | ϕ | | ± 22 | | deg |
| Forward voltage | $I_F = 20 \text{ mA}$ | | V_F | | 2.4 | 3 | V |
| Reverse voltage | $I_R = 10 \text{ }\mu\text{A}$ | | V_R | 6 | 15 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 50 | | pF |

¹⁾ in one Packing Unit $I_{Vmin}/I_{Vmax} \leq 0.5$

Pure green

TLHP42..

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|----------------------------------|--------------------------------|----------|-------------|-----|----------|-----|------|
| Luminous intensity ¹⁾ | $I_F = 10 \text{ mA}$ | TLHP4200 | I_V | 2.5 | 7 | | mcd |
| | | TLHP4201 | I_V | 6.3 | | 20 | mcd |
| Dominant wavelength | $I_F = 10 \text{ mA}$ | | λ_d | 555 | | 565 | nm |
| Peak wavelength | $I_F = 10 \text{ mA}$ | | λ_p | | 555 | | nm |
| Angle of half intensity | $I_F = 10 \text{ mA}$ | | ϕ | | ± 22 | | deg |
| Forward voltage | $I_F = 20 \text{ mA}$ | | V_F | | 2.4 | 3 | V |
| Reverse voltage | $I_R = 10 \text{ }\mu\text{A}$ | | V_R | 6 | 15 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 50 | | pF |

¹⁾ in one Packing Unit $I_{Vmin}/I_{Vmax} \leq 0.5$

Typical Characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)



Figure 1. Power Dissipation vs. Ambient Temperature



Figure 4. Rel. Luminous Intensity vs. Angular Displacement



Figure 2. Forward Current vs. Ambient Temperature for InGaN



Figure 5. Forward Current vs. Forward Voltage



Figure 3. Forward Current vs. Pulse Length



Figure 6. Rel. Luminous Intensity vs. Ambient Temperature



Figure 7. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle



Figure 10. Forward Current vs. Forward Voltage



Figure 8. Relative Luminous Intensity vs. Forward Current



Figure 11. Rel. Luminous Intensity vs. Ambient Temperature

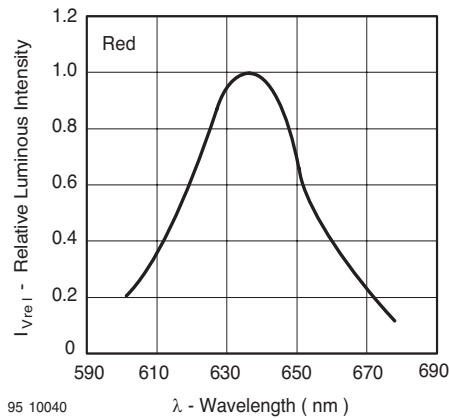


Figure 9. Relative Intensity vs. Wavelength



Figure 12. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle



Figure 13. Relative Luminous Intensity vs. Forward Current



Figure 16. Rel. Luminous Intensity vs. Ambient Temperature



Figure 14. Relative Intensity vs. Wavelength



Figure 17. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle



Figure 15. Forward Current vs. Forward Voltage

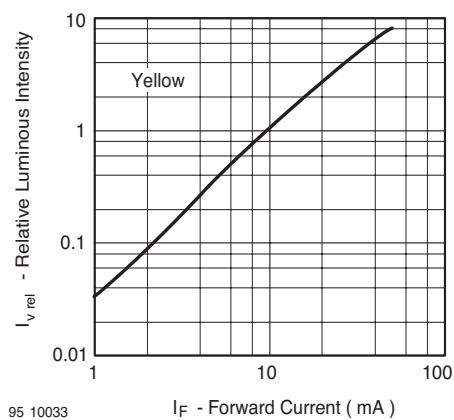


Figure 18. Relative Luminous Intensity vs. Forward Current



Figure 19. Relative Intensity vs. Wavelength



Figure 22. Specific Luminous Intensity vs. Forward Current



Figure 20. Forward Current vs. Forward Voltage



Figure 23. Relative Luminous Intensity vs. Forward Current



Figure 21. Rel. Luminous Intensity vs. Ambient Temperature



Figure 24. Relative Intensity vs. Wavelength



Figure 25. Forward Current vs. Forward Voltage



Figure 28. Relative Luminous Intensity vs. Forward Current



Figure 26. Rel. Luminous Intensity vs. Ambient Temperature



Figure 29. Relative Intensity vs. Wavelength



Figure 27. Specific Luminous Intensity vs. Forward Current



Package Dimensions in mm



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design
and may do so without further notice.**

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Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423

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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

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Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9